



MBR10100CT THRU MBR10200CT

10.0 AMPS. Schottky Barrier Rectifiers



Voltage Range
100 to 200 Volts
Current
10.0 Amperes

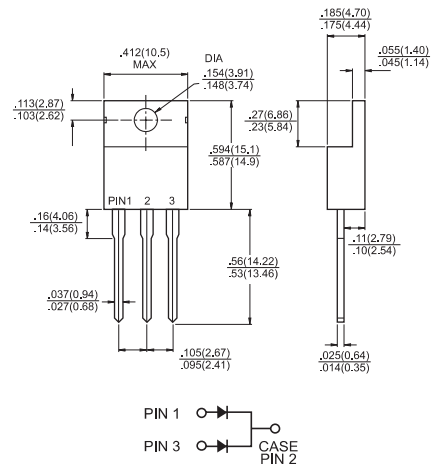
Features

- ✧ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ✧ Metal silicon junction, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ High current capability, low forward voltage drop
- ✧ High surge capability
- ✧ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✧ Guardring for overvoltage protection
- ✧ High temperature soldering guaranteed:
260°C/10 seconds, 0.25" (6.35mm) from case

Mechanical Data

- ✧ Cases: JEDEC TO-220 molded plastic body
- ✧ Terminals: Lead solderable per MIL-STD-750, Method 2026
- ✧ Polarity: As marked
- ✧ Mounting position: Any
- ✧ Mounting torque: 5 in. - lbs. max
- ✧ Weight: 0.08 ounce, 2.24 grams

TO-220



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBR 10100CT	MBR 10150CT	MBR 10200CT	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	100	150	200	V
Maximum RMS Voltage	V_{RMS}	70	105	140	V
Maximum DC Blocking Voltage	V_{DC}	100	150	200	V
Maximum Average Forward Rectified Current at $T_c=125^\circ\text{C}$	$I_{(AV)}$	10			A
Peak Repetitive Forward Current (Rated V_F , Square Wave, 20KHz) at $T_c=125^\circ\text{C}$	I_{FRM}	32.0			A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	120			A
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	0.5			A
Maximum Instantaneous Forward Voltage at: (Note 2) $I_F=5A, T_c=25^\circ\text{C}$ $I_F=5A, T_c=125^\circ\text{C}$	V_F	0.85 0.75	0.88 0.78	0.99 0.87	V
Maximum Instantaneous Reverse Current @ $T_c=25^\circ\text{C}$ at Rated DC Blocking Voltage (Note 2)	I_R	0.008			0.2 mA
Voltage Rate of Change (Rated V_R)	dV/dt	10,000			V/ μS
Maximum Typical Thermal Resistance (Note 3)	R_{θ_c}	1.5			$^\circ\text{C}/\text{W}$
Operating Junction Temperature Range	T_J	-65 to +150			$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +175			$^\circ\text{C}$

Notes: 1. 2.0 μs Pulse Width, $f=1.0\text{ KHz}$

2. Pulse Test: 300 μs Pulse Width, 1% Duty Cycle

3. Thermal Resistance from Junction to Case Per Leg, Mount on Heatsink Size of 2 in x 3 in x 0.25 in Al-Plate.

RATINGS AND CHARACTERISTIC CURVES (MBR10100CT THRU MBR10200CT)

FIG.1- FORWARD CURRENT DERATING CURVE

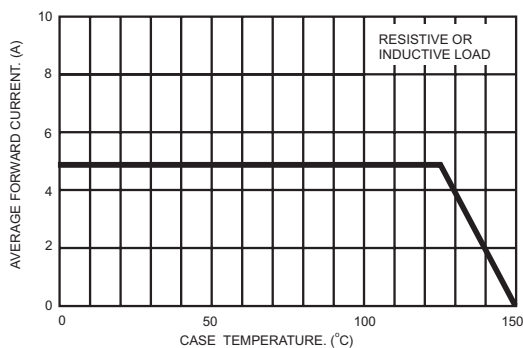


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

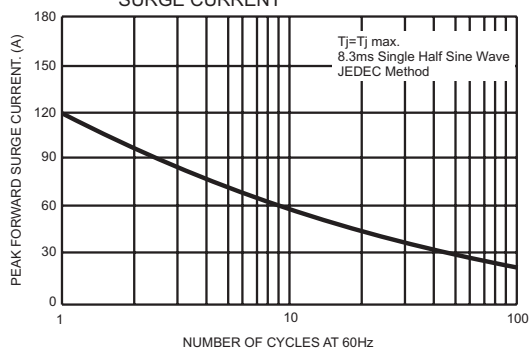


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

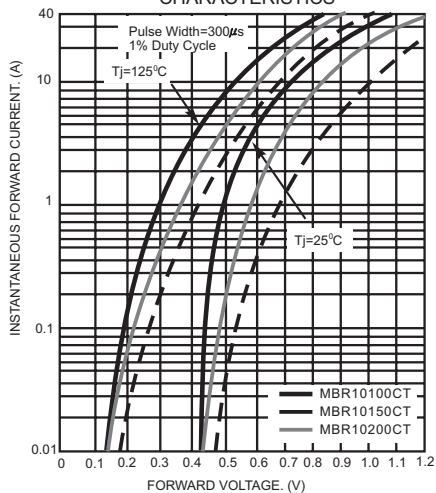


FIG.4- TYPICAL REVERSE CHARACTERISTICS

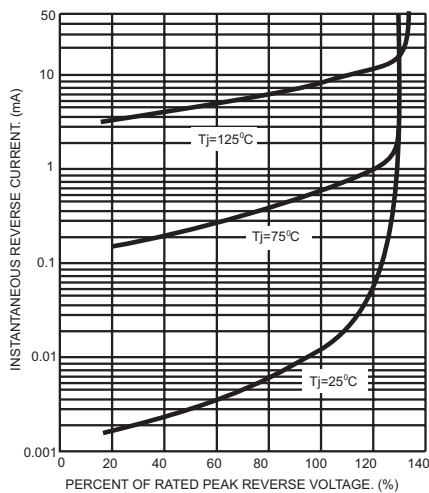


FIG.5- TYPICAL JUNCTION CAPACITANCE

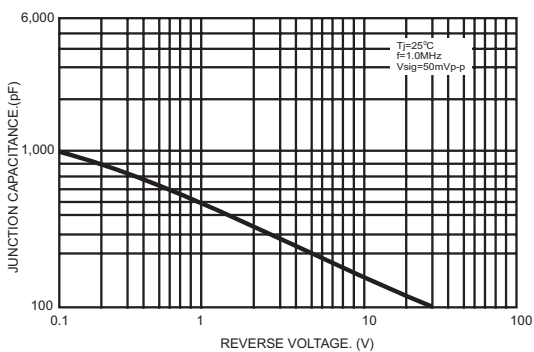


FIG.6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS

